



10A05 THRU 10A10 SILICON RECTIFIER

FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Open-Junction chip ,silastic passivated
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed 250°C/10 seconds at terminals

MECHANICAL DATA

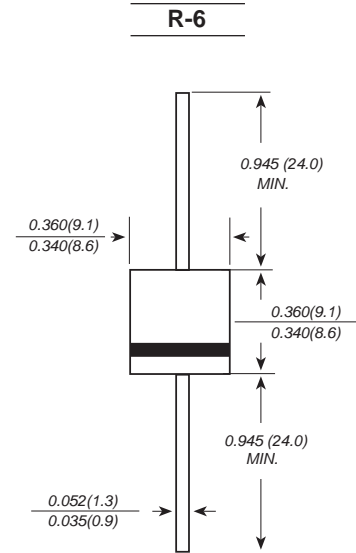
Case: JEDEC R-6 molded plastic body

Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight : 0.072 ounce, 2.05 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	SYMBOLS	10A05	10A1	10A2	10A3	10A4	10A6	10A8	10A10	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	300	400	600	800	1000	VOLTS
Maximum RMS voltage	V_{RMS}	35	70	140	210	280	420	560	700	VOLTS
Maximum DC blocking voltage	V_{DC}	50	100	200	300	400	600	800	1000	VOLTS
Maximum average forward rectified current at $T_L=60^\circ\text{C}$	$I_{(AV)}$	10.0								Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	400								Amps
Maximum instantaneous forward voltage at 10.0A	V_F	1.0								Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	10.0 100.0								μA
Typical junction capacitance (Note 1)	C_J	150								pF
Typical thermal resistance (Note 2)	R_{qJA}	10								$^\circ\text{C/W}$
Operating junction and storage temperature range	T_J, T_{STG}	-55 to +125								$^\circ\text{C}$

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted



10A05 THRU 10A10 SILICON RECTIFIER

RATINGS AND CHARACTERISTIC CURVES

FIG. 1- FORWARD CURRENT DERATING CURVE

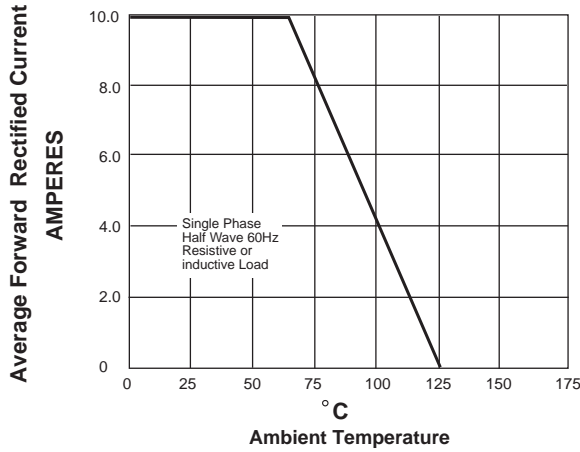


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

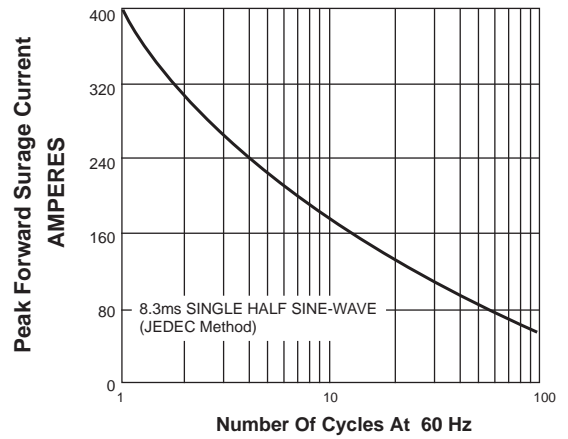


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

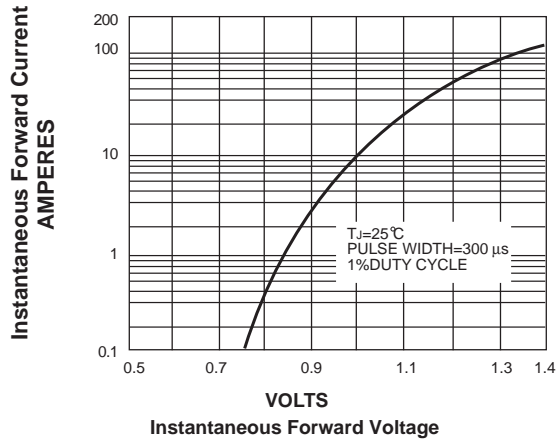


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

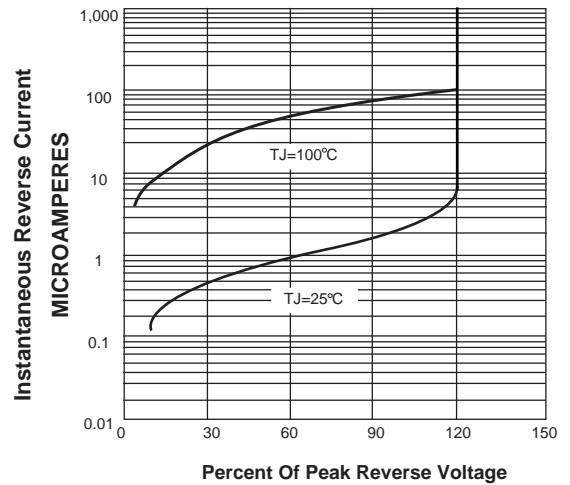


FIG. 5-TYPICAL JUNCTION CAPACITANCE

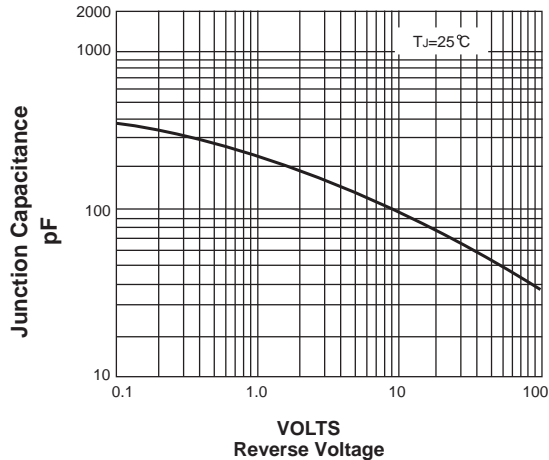
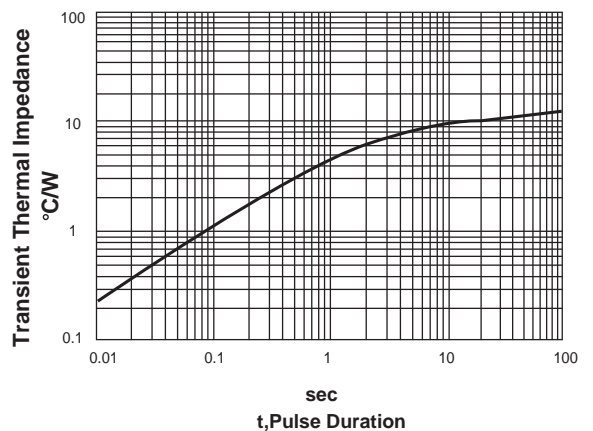


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Diodes - General Purpose, Power, Switching category:](#)

Click to view products by [Juxing Electronic Technology manufacturer:](#)

Other Similar products are found below :

[MCL4151-TR3](#) [MMBD3004S-13-F](#) [RD0306T-H](#) [1N3611](#) [NTE156A](#) [NTE574](#) [NTE6244](#) [1SS193,LF](#) [1SS400CST2RA](#) [SDAA13](#)
[SHN2D02FUTW1T1G](#) [LS4151GS08](#) [1N4449](#) [1N456A](#) [1N4934-E3/73](#) [1N914BTR](#) [RFUH20TB3S](#) [D291S45T](#) [BAV300-TR](#) [BAW56DWQ-](#)
[7-F](#) [BAW75-TAP](#) [MM230L-CAA](#) [IDW40E65D1](#) [JAN1N3600](#) [JAN1N4454UR-1](#) [LL4151-GS18](#) [SMMSD4148T3G](#) [BYW95B/A52A](#)
[NSVDAN222T1G](#) [CDSZC01100-HF](#) [LL4150-M-08](#) [1N4454-TR](#) [BAV70HDW-7](#) [BAS28-7](#) [JANTX1N6640](#) [BAW56HDW-13](#) [BAS28 TR](#)
[VS-HFA04SD60STR-M3](#) [NSVM1MA152WKT1G](#) [1SS388-TP](#) [RGP30D-E3/73](#) [VS-8EWF02S-M3](#) [BAV99TQ-13-F](#) [BAV99HDW-13](#)
[MMDB30-E28X](#) [IDP20C65D2XKSA1](#) [LS4148](#) [IDV15E65D2](#) [NSVM1MA152WAT1G](#) [HN4D02JU\(TE85L,F\)](#)